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- Paper structure:
 - Title of the paper
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 - Date when paper was sent to the Editor-in-Chief of CM&NT
 - The abstract of the paper
 - Keywords
 - Body text
 - Conclusions
 - Acknowledgments (optional)
 - References (Cyrillic sources should be written in transliteration)
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- Equations should be
 - written using **MathType Equation Editor**;
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 - when referring to an equation in the text, always put the equation number in brackets - e.g. 'as in Equation (2)'
- References should be:
 - listed at the end of the paper;
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 - If you are citing a work written in a nonLatin script (e.g., Chinese, Greek, Japanese, Russian etc.), the reference must be transliterated into the English alphabet, the reference should be accompanied by remark, e.g., (in Russian), (in Japanese), (in Chinese)
- Please do not use *Page breaks*, *Section breaks* etc. while formatting
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References (examples):

The final page number should be in the shortest possible form and separated from the initial page number by an en rule ‘–’, e.g. 2104–14, i.e. the numbers ‘21’ are not repeated

Journal articles

- [1] Shunin Yu N, Zhukovskii Yu F, Gopejenko V I, Burlutskaya N, Lobanova-Shunina T, Bellucci S 2012 *Journal of Nanophotonics* **6**(1) 31-6

Books

- [2] Ziman J M 1979 *Models of Disorder* Cambridge Univ. Press: New York-London chapter 10
- [3] Economou E L 2006 *Green's Functions in Quantum Physics* (3rd edition) *Solid State Ser. 7* Springer Verlag: Berlin-Heidelberg
- [4] Sze S M 1969 *Physics of Semiconductor Devices* Wiley Interscience: New York
- [5] Shunin Yu N, Zhukovskii Yu F, Burlutskaya N Yu, Gopejenko V I, Bellucci S 2012 in *Nanodevices and Nanomaterials for Ecological Security, Series: NATO Science for Peace Series B - Physics and Biophysics* ed Yu Shunin and A Kiv Springer Verlag: Hiedelberg 237-62

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- [6] Dorman L I 1975 *Variations of Galactic Cosmic Rays* Moscow State University Press: Moscow p 103
- [7] Caplar R and Kulisic P 1973 *Proc. Int. Conf. on Nuclear Physics (Munich)* **1** North-Holland/American Elsevier: Amsterdam p 517
- [8] Cheng G X 2001 *Raman and Brillouin Scattering-Principles and Applications* Scientific: Beijing
- [9] Szytula A and Leciejewicz J 1989 *Handbook on the Physics and Chemistry of Rare Earths* **12** ed K A Gschneidner Jr and L Erwin Elsevier: Amsterdam p 133
- [10] Kuhn T 1998 Density matrix theory of coherent ultrafast dynamics *Theory of Transport Properties of Semiconductor Nanostructures (Electronic Materials 4)* ed E Schöll Chapman and Hall: London **chapter 6** 173–214
- [11] Kuhn T, Binder E, Rossi F, Lohner A, Rick K, Leisching P, Leitenstorfer A, Elsaesser T, Stolz W 1994 Coherent excitonic and free-carrier dynamics in bulk GaAs and heterostructures *Coherent Optical Interactions in Semiconductors: Proc. NATO Advanced Research Workgroup (Cambridge, UK, 11–14 August 1993) NATO Advanced Study Institute, Series B: Physics* **330** ed R T Phillips Plenum: New York 33–62

Preprints and Patents

- [12] Milson R, Coley A, Pravda V, Pravdova A 2004 Alignment and algebraically special tensors *Preprint* gr-qc/0401010
- [13] Eaton D I 1975 *Porous glass support material* US Patent No. 3 904

Internet recourses

- [14] Ram R, Orlando T 2003 *Physics for Solid-State Applications* <http://ocw.mit.edu/courses/electrical-engineering-and-computer-science/6-730-physics-for-solid-state-applications-spring-2003/> 16 Jan 2014

Work written in a nonLatin script

- [15] Grosberg A. Yu. and Khokhlov A. R., 1989 *Statistical Physics of Macromolecules* Nauka: Moscow (*in Russian*)
- [16] Kireev S V, Protsenko E D, Shyrev S L 2002 *Byull. Izobret.* No. 10 RF Patent No.2181197 (*in Russian*)

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*Corresponding author's e-mail: user@gmail.com

Received 1 April 2017, www.isma.lv

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2 Another section of the paper

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2.1 A SUBSECTION

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Figure

FIGURE 1 Figure title

Figure

FIGURE 2 Figure title

Figure

FIGURE 3 Figure title

TABLE 1 Table title

Column title	Column title	Column title
Text	Text	Text
Text	Text	Text

$$\hat{S}_\alpha(t, M) = \sum_{k=1}^M (\hat{a}_k \sin(\hat{x}_k t) X_k + \hat{b}_k (1 - \cos(\hat{y}_k t)) Y_k) \quad (1)$$

2.2.1 A subsubsection

The first paragraph after a heading is not indented.

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3 Conclusions**Acknowledgements****Appendix A Appendix title****References**

- [1] Tallman D E, Wallace G G 1997 *Synth. Met.* **90** 13
- [2] Kroto H W, Fischer J E, Cox D E 1993 *The Fullerenes* Pergamon: Oxford
- [3] MacDiarmid A G, Epstein A J 1991 in ed. W R Salaneck, D T Clark, E J Samuelson *Science and Applications of Conducting Polymers* Adam Hilger: Bristol p 117
- [4] Eaton D I 1975 *Porous glass support material* US Patent No. 3 904

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